# 500 mW DO-35 Hermetically Sealed Glass Zener Voltage Regulators

This is a complete series of 500 mW Zener diodes with limits and excellent operating characteristics that reflect the superior capabilities of silicon–oxide passivated junctions. All this in an axial–lead hermetically sealed glass package that offers protection in all common environmental conditions.

## **Specification Features:**

- Zener Voltage Range 2.4 V to 91 V
- ESD Rating of Class 3 (>16 KV) per Human Body Model
- DO-204AH (DO-35) Package Smaller than Conventional DO-204AA Package
- Double Slug Type Construction
- Metallurgical Bonded Construction

#### **Mechanical Characteristics:**

CASE: Double slug type, hermetically sealed glass

FINISH: All external surfaces are corrosion resistant and leads are

readily solderable

#### **MAXIMUM LEAD TEMPERATURE FOR SOLDERING PURPOSES:**

230°C, 1/16" from the case for 10 seconds **POLARITY:** Cathode indicated by polarity band

**MOUNTING POSITION:** Any

## MAXIMUM RATINGS (Note 1.)

Rating	Symbol	Value	Unit
Max. Steady State Power Dissipation @ T <sub>L</sub> ≤ 75°C, Lead Length = 3/8" Derate above 75°C	P <sub>D</sub>	500 4.0	mW mW/°C
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +200	°C

1. Some part number series have lower JEDEC registered ratings.



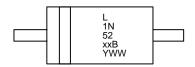
## ON Semiconductor™

## http://onsemi.com





## **MARKING DIAGRAM**



L = Assembly Location 1N52xxB = Device Code

(See Table Next Page)

= Year = Work Week

WW

## **ORDERING INFORMATION**

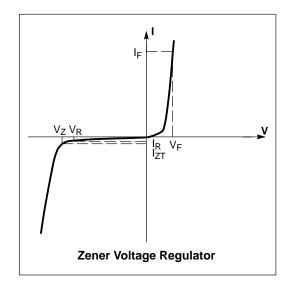
Device	Package	Shipping		
1N52xxB	Axial Lead	3000 Units/Box		
1N52xxBRL	Axial Lead	5000/Tape & Reel		
1N52xxBRL2 *	Axial Lead	5000/Tape & Reel		
1N52xxBRA1	Axial Lead	3000/Ammo Pack		
1N52xxBTA	Axial Lead	5000/Ammo Pack		
1N52xxBTA2 *	Axial Lead	5000/Ammo Pack		
1N52xxBRR1 <sup>†</sup>	Axial Lead	3000/Tape & Reel		
1N52xxBRR2 <sup>‡</sup>	Axial Lead	3000/Tape & Reel		

- The "2" suffix refers to 26 mm tape spacing.
- Polarity band **up** with cathode lead off first
- <sup>‡</sup> Polarity band **down** with cathode lead off first

Devices listed in *bold, italic* are ON Semiconductor **Preferred** devices. **Preferred** devices are recommended choices for future use and best overall value.

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}$ C unless otherwise noted, Based on dc measurements at thermal equilibrium; lead length = 3/8"; thermal resistance of heat sink =  $30^{\circ}$ C/W,  $V_F = 1.1$  V Max @  $I_F = 200$  mA for all types)

Symbol	Parameter						
V <sub>Z</sub>	Reverse Zener Voltage @ I <sub>ZT</sub>						
I <sub>ZT</sub>	Reverse Current						
Z <sub>ZT</sub>	Maximum Zener Impedance @ I <sub>ZT</sub>						
I <sub>ZK</sub>	Reverse Current						
Z <sub>ZK</sub>	Maximum Zener Impedance @ I <sub>ZK</sub>						
I <sub>R</sub>	Reverse Leakage Current @ V <sub>R</sub>						
V <sub>R</sub>	Breakdown Voltage						
l <sub>F</sub>	Forward Current						
V <sub>F</sub>	Forward Voltage @ I <sub>F</sub>						
$\theta_{VZ}$	Maximum Zener Voltage Temperature Coefficient						



**ELECTRICAL CHARACTERISTICS** ( $T_A = 25$ °C unless otherwise noted, Based on dc measurements at thermal equilibrium; lead length = 3/8"; thermal resistance of heat sink = 30°C/W,  $V_F = 1.1$  V Max @  $I_F = 200$  mA for all types)

		Zener Voltage (Note 3.)			Zener Impedance (Note 4.)			Leakage Current		θvz	
Device	Device		V <sub>Z</sub> (Volts)		@ I <sub>ZT</sub>	Z <sub>ZT</sub> @ I <sub>ZT</sub>	Z <sub>ZK</sub> @ I <sub>ZK</sub>		I <sub>R</sub> @ V <sub>R</sub>		(Note 5.)
(Note 2.)	Marking	Min	Nom	Max	mA	Ω	Ω	mA	μ <b>Α</b>	Volts	%/°C
1N5221B	1N5221B	2.28	2.4	2.52	20	30	1200	0.25	100	1	-0.085
1N5222B	1N5222B	2.375	2.5	2.625	20	30	1250	0.25	100	1	-0.085
1N5223B	1N5223B	2.565	2.7	2.835	20	30	1300	0.25	75	1	-0.08
1N5224B	1N5224B	2.66	2.8	2.94	20	30	1400	0.25	75	1	-0.08
1N5225B	1N5225B	2.85	3.0	3.15	20	29	1600	0.25	50	1	-0.075
1N5226B	1N5226B	3.14	3.3	3.46	20	28	1600	0.25	25	1	-0.07
1N5227B	1N5227B	3.42	3.6	3.78	20	24	1700	0.25	15	1	-0.065
1N5228B	1N5228B	3.71	3.9	4.09	20	23	1900	0.25	10	1	-0.06
1N5229B	1N5229B	4.09	4.3	4.51	20	22	2000	0.25	5	1	±0.055
1N5230B	1N5230B	4.47	4.7	4.93	20	19	1900	0.25	5	2	±0.03
1N5231B	1N5231B	4.85	5.1	5.35	20	17	1600	0.25	5	2	±0.03
1N5232B	1N5232B	5.32	5.6	5.88	20	11	1600	0.25	5	3	0.038
1N5233B	1N5233B	5.7	6.0	6.3	20	7	1600	0.25	5	3.5	0.038
1N5234B	1N5234B	5.89	6.2	6.51	20	7	1000	0.25	5	4	0.045
1N5235B	1N5235B	6.46	6.8	7.14	20	5	750	0.25	3	5	0.05

## 2. TOLERANCE

The JEDEC type numbers shown indicate a tolerance of ±5%.

## 3. ZENER VOLTAGE (V<sub>Z</sub>) MEASUREMENT

The zener voltage is measured with the device junction in the thermal equilibrium at the lead temperature ( $T_L$ ) at 30°C  $\pm$  1°C and 3/8" lead length.

## 4. ZENER IMPEDANCE (Z<sub>Z</sub>) DERIVATION

 $Z_{ZT}$  and  $Z_{ZK}$  are measured by dividing the ac voltage drop across the device by the ac current applied. The specified limits are for  $I_{Z(ac)} = 0.1 I_{Z(dc)}$  with the ac frequency = 60 Hz.

## 5. TEMPERATURE COEFFICIENT (θ<sub>VZ</sub>) \*

Test conditions for temperature coefficient are as follows:

- A.  $I_{ZT} = 7.5$  mA,  $T_1 = 25$ °C,  $T_2 = 125$ °C (1N5221B through 1N5242B)
- B.  $I_{ZT}$  = Rated  $I_{ZT}$ ,  $T_1$  = 25°C,  $T_2$  = 125°C (1N5243B through 1N5281B)

Device to be temperature stabilized with current applied prior to reading breakdown voltage at the specified ambient temperature.

<sup>\*</sup> For more information on special selections contact your nearest ON Semiconductor representative.

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}\text{C}$  unless otherwise noted, Based on dc measurements at thermal equilibrium; lead length = 3/8''; thermal resistance of heat sink =  $30^{\circ}\text{C/W}$ ,  $V_F = 1.1 \text{ V Max}$  @  $I_F = 200 \text{ mA}$  for all types) (continued)

		Zener Voltage (Note 7.)			Zener Impedance (Note 8.)		Leakage Current		θ <sub>VZ</sub>		
Device	Device		V <sub>Z</sub> (Volts)		@ l <sub>ZT</sub>	Z <sub>ZT</sub> @ I <sub>ZT</sub>	Z <sub>ZK</sub> @ I <sub>ZK</sub>		I <sub>R</sub> @ V <sub>R</sub>		(Note 9.)
(Note 6.)	Marking	Min	Nom	Max	mA	Ω	Ω	mA	μ <b>Α</b>	Volts	%/°C
1N5236B	1N5236B	7.13	7.5	7.87	20	6	500	0.25	3	6	0.058
1N5237B	1N5237B	7.79	8.2	8.61	20	8	500	0.25	3	6.5	0.062
1N5238B	1N5238B	8.265	8.7	9.135	20	8	600	0.25	3	6.5	0.065
1N5239B	1N5239B	8.65	9.1	9.55	20	10	600	0.25	3	7	0.068
1N5240B	1N5240B	9.5	10	10.5	20	17	600	0.25	3	8	0.075
1N5241B	1N5241B	10.45	11	11.55	20	22	600	0.25	2	8.4	0.076
1N5242B	1N5242B	11.4	12	12.6	20	30	600	0.25	1	9.1	0.077
1N5243B	1N5243B	12.35	13	13.65	9.5	13	600	0.25	0.5	9.9	0.079
1N5244B	1N5244B	13.3	14	14.7	9	15	600	0.25	0.1	10	0.082
1N5245B	1N5245B	14.25	15	15.75	8.5	16	600	0.25	0.1	11	0.082
1N5246B	1N5246B	15.2	16	16.8	7.8	17	600	0.25	0.1	12	0.083
1N5247B	1N5247B	16.15	17	17.85	7.4	19	600	0.25	0.1	13	0.084
1N5248B	1N5248B	17.1	18	18.9	7	21	600	0.25	0.1	14	0.085
1N5249B	1N5249B	18.05	19	19.95	6.6	23	600	0.25	0.1	14	0.086
1N5250B	1N5250B	19	20	21	6.2	25	600	0.25	0.1	15	0.086
1N5251B	1N5251B	20.9	22	23.1	5.6	29	600	0.25	0.1	17	0.087
1N5252B	1N5252B	22.8	24	25.2	5.2	33	600	0.25	0.1	18	0.088
1N5253B	1N5253B	23.75	25	26.25	5.0	35	600	0.25	0.1	19	0.089
1N5254B	1N5254B	25.65	27	28.35	4.6	41	600	0.25	0.1	21	0.090
1N5255B	1N5255B	26.6	28	29.4	4.5	44	600	0.25	0.1	21	0.091
1N5256B	1N5256B	28.5	30	31.5	4.2	49	600	0.25	0.1	23	0.091
1N5257B	1N5257B	31.35	33	34.65	3.8	58	700	0.25	0.1	25	0.092
1N5258B	1N5258B	34.2	36	37.8	3.4	70	700	0.25	0.1	27	0.093
1N5259B	1N5259B	37.05	39	40.95	3.2	80	800	0.25	0.1	30	0.094
1N5260B	1N5260B	40.85	43	45.15	3.0	93	900	0.25	0.1	33	0.095
1N5261B	1N5261B	44.65	47	49.35	2.7	105	1000	0.25	0.1	36	0.095
1N5262B	1N5262B	48.45	51	53.55	2.5	125	1100	0.25	0.1	39	0.096
1N5263B	1N5263B	53.2	56	58.8	2.2	150	1300	0.25	0.1	43	0.096
1N5264B	1N5264B	57	60	63	2.1	170	1400	0.25	0.1	46	0.097
1N5265B	1N5265B	58.9	62	65.1	2.0	185	1400	0.25	0.1	47	0.097
1N5266B	1N5266B	64.6	68	71.4	1.8	230	1600	0.25	0.1	52	0.097
1N5267B	1N5267B	71.25	75	78.75	1.7	270	1700	0.25	0.1	56	0.098
1N5268B	1N5268B	77.9	82	86.1	1.5	330	2000	0.25	0.1	62	0.098
1N5269B	1N5269B	82.65	87	91.35	1.4	370	2200	0.25	0.1	68	0.099
1N5270B	1N5270B	86.45	91	95.55	1.4	400	2300	0.25	0.1	69	0.099

## 6. TOLERANCE

The JEDEC type numbers shown indicate a tolerance of ±5%.

## 7. ZENER VOLTAGE (VZ) MEASUREMENT

The zener voltage is measured with the device junction in the thermal equilibrium at the lead temperature ( $T_L$ ) at 30°C  $\pm$  1°C and 3/8" lead length.

## 8. ZENER IMPEDANCE (Z<sub>Z</sub>) DERIVATION

 $Z_{ZT}$  and  $Z_{ZK}$  are measured by dividing the ac voltage drop across the device by the ac current applied. The specified limits are for  $I_{Z(ac)} = 0.1 I_{Z(dc)}$  with the ac frequency = 60 Hz.

## 9. TEMPERATURE COEFFICIENT (θ<sub>VZ</sub>) \*

Test conditions for temperature coefficient are as follows:

A.  $I_{ZT} = 7.5$  mA,  $T_1 = 25$ °C,  $T_2 = 125$ °C (1N5221B through 1N5242B)

B.  $I_{ZT}$  = Rated  $I_{ZT}$ ,  $T_1$  = 25°C,  $T_2$  = 125°C (1N5243B through 1N5281B)

Device to be temperature stabilized with current applied prior to reading breakdown voltage at the specified ambient temperature.

<sup>\*</sup> For more information on special selections contact your nearest ON Semiconductor representative.

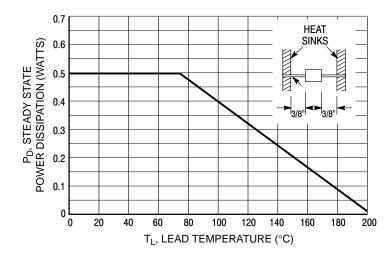


Figure 1. Steady State Power Derating

#### **APPLICATION NOTE — ZENER VOLTAGE**

Since the actual voltage available from a given zener diode is temperature dependent, it is necessary to determine junction temperature under any set of operating conditions in order to calculate its value. The following procedure is recommended:

Lead Temperature, T<sub>L</sub>, should be determined from:

$$T_L = \theta_{LA} P_D + T_A$$
.

 $\theta_{LA}$  is the lead-to-ambient thermal resistance (°C/W) and  $P_D$  is the power dissipation. The value for  $\theta_{LA}$  will vary and depends on the device mounting method.  $\theta_{LA}$  is generally 30 to 40°C/W for the various clips and tie points in common use and for printed circuit board wiring.

The temperature of the lead can also be measured using a thermocouple placed on the lead as close as possible to the tie point. The thermal mass connected to the tie point is normally large enough so that it will not significantly respond to heat surges generated in the diode as a result of pulsed operation once steady-state conditions are achieved. Using the measured value of  $T_L$ , the junction temperature may be determined by:

$$\mathsf{T}_\mathsf{J} = \mathsf{T}_\mathsf{L} + \Delta \mathsf{T}_\mathsf{JL}.$$

 $\Delta T_{JL}$  is the increase in junction temperature above the lead temperature and may be found from Figure 2 for dc power:

$$\Delta T_{JL} = \theta_{JL} P_D$$
.

For worst-case design, using expected limits of  $I_Z$ , limits of  $P_D$  and the extremes of  $T_J(\Delta T_J)$  may be estimated. Changes in voltage,  $V_Z$ , can then be found from:

$$\Delta V = \theta_{VZ} T_{J}$$
.

 $\theta_{VZ}\!,$  the zener voltage temperature coefficient, is found from Figures 4 and 5.

Under high power-pulse operation, the zener voltage will vary with time and may also be affected significantly by the zener resistance. For best regulation, keep current excursions as low as possible.

Surge limitations are given in Figure 7. They are lower than would be expected by considering only junction temperature, as current crowding effects cause temperatures to be extremely high in small spots, resulting in device degradation should the limits of Figure 7 be exceeded.

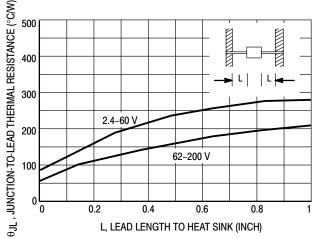


Figure 2. Typical Thermal Resistance

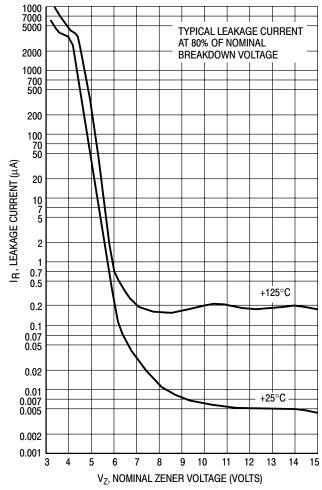
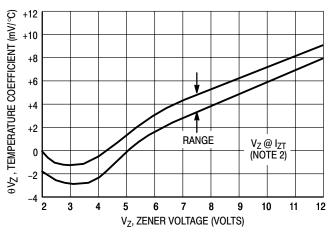


Figure 3. Typical Leakage Current

## **TEMPERATURE COEFFICIENTS**

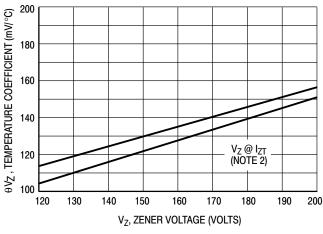
(-55°C to +150°C temperature range; 90% of the units are in the ranges indicated.)



 $\theta V_{\mbox{\scriptsize Z}}$  , TEMPERATURE COEFFICIENT (mV/ $^{\circ}\mbox{\scriptsize C})$ 70 50 30 20 Vz@ Iz (NOTE 2) 10 7 5 10 20 30 50 70 100 V<sub>7</sub>, ZENER VOLTAGE (VOLTS)

Figure 4a. Range for Units to 12 Volts

Figure 4b. Range for Units 12 to 100 Volts



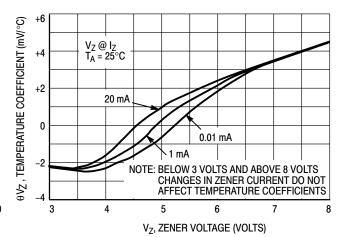
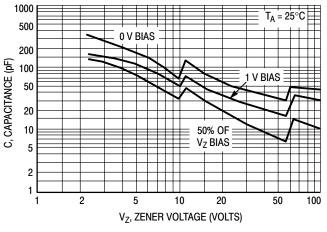


Figure 4c. Range for Units 120 to 200 Volts

Figure 5. Effect of Zener Current



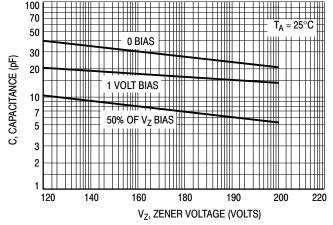


Figure 6a. Typical Capacitance 2.4-100 Volts

Figure 6b. Typical Capacitance 120-200 Volts

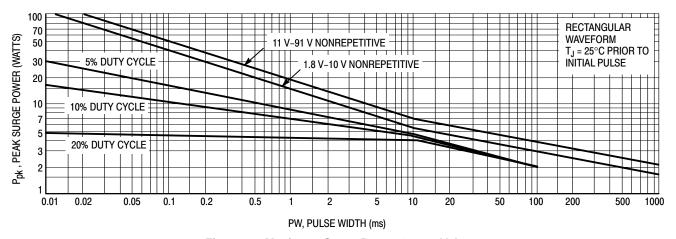


Figure 7a. Maximum Surge Power 1.8-91 Volts

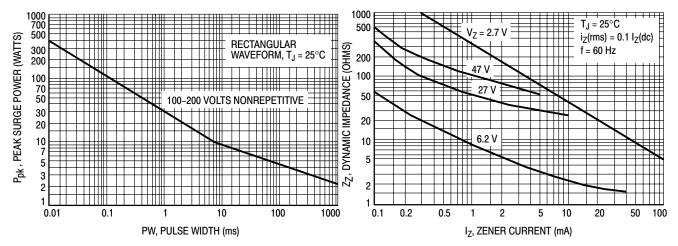


Figure 7b. Maximum Surge Power DO-204AH 100–200 Volts

Figure 8. Effect of Zener Current on Zener Impedance

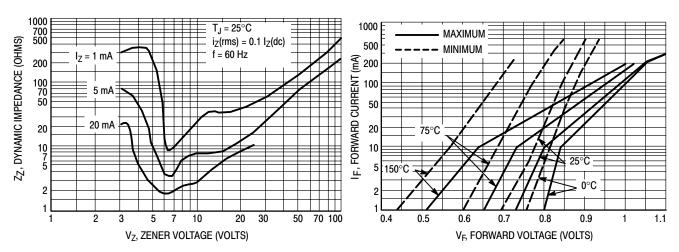


Figure 9. Effect of Zener Voltage on Zener Impedance

Figure 10. Typical Forward Characteristics

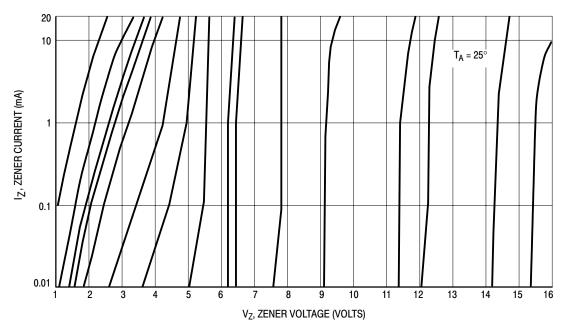


Figure 11. Zener Voltage versus Zener Current —  $V_Z = 1$  thru 16 Volts

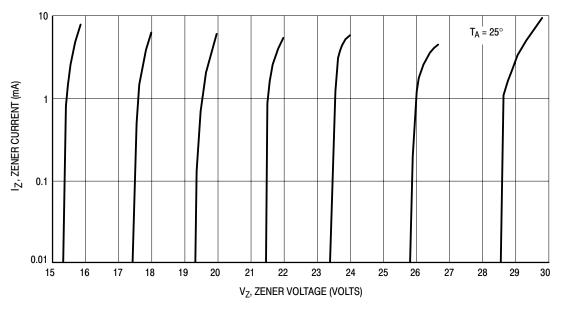


Figure 12. Zener Voltage versus Zener Current —  $V_Z$  = 15 thru 30 Volts

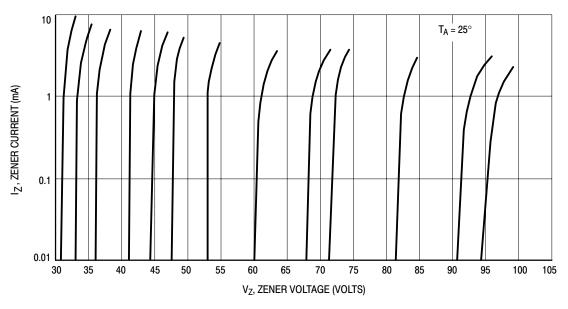


Figure 13. Zener Voltage versus Zener Current —  $V_Z = 30$  thru 105 Volts

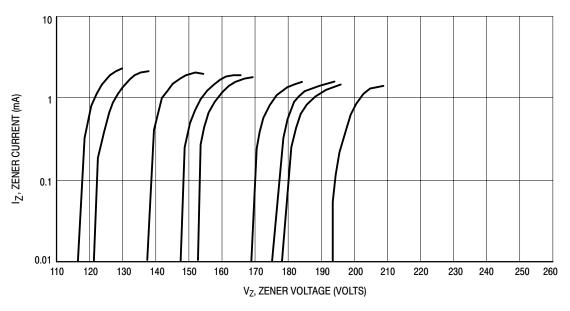


Figure 14. Zener Voltage versus Zener Current —  $V_Z$  = 110 thru 220 Volts

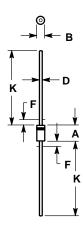
## **OUTLINE DIMENSIONS**

# Zener Voltage Regulators – Axial Leaded

# 500 mW DO-35 Glass

## GLASS DO-35/D0-204AH

CASE 299-02 ISSUE A



- NOTES:

  1. PACKAGE CONTOUR OPTIONAL WITHIN A AND B HEAT SLUGS, IF ANY, SHALL BE INCLUDED WITHIN THIS CYLINDER, BUT NOT SUBJECT TO THE MINIMUM LIMIT OF B.

  2. LEAD DIAMETER NOT CONTROLLED IN ZONE F TO ALLOW FOR FLASH, LEAD FINISH BUILDUP AND MINOR IRREGULARITIES OTHER THAN HEAT SLUGS.

  3. POLARITY DENOTED BY CATHODE BAND.
- 3. POLARITY DENOTED BY CATHODE BAND.
  4. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

	MILLIN	METERS	INCHES			
DIM	MIN	MIN MAX		MAX		
Α	3.05	5.08	0.120	0.200		
В	1.52	2.29	0.060	0.090		
D	0.46	0.56	0.018	0.022		
F		1.27		0.050		
K	25.40	38.10	1.000	1.500		

All JEDEC dimensions and notes apply.

# **Notes**

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer.

#### **PUBLICATION ORDERING INFORMATION**

## NORTH AMERICA Literature Fulfillment:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA

Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada

Email: ONlit@hibbertco.com

Fax Response Line: 303-675-2167 or 800-344-3810 Toll Free USA/Canada

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

EUROPE: LDC for ON Semiconductor - European Support

German Phone: (+1) 303-308-7140 (Mon-Fri 2:30pm to 7:00pm CET) Email: ONlit-german@hibbertco.com

Phone: (+1) 303–308–7141 (Mon–Fri 2:00pm to 7:00pm CET)

Email: ONlit-french@hibbertco.com

English Phone: (+1) 303-308-7142 (Mon-Fri 12:00pm to 5:00pm GMT)

Email: ONlit@hibbertco.com

EUROPEAN TOLL-FREE ACCESS\*: 00-800-4422-3781

\*Available from Germany, France, Italy, UK, Ireland

## **CENTRAL/SOUTH AMERICA:**

Spanish Phone: 303-308-7143 (Mon-Fri 8:00am to 5:00pm MST)

Email: ONlit-spanish@hibbertco.com

Toll-Free from Mexico: Dial 01-800-288-2872 for Access -

then Dial 866-297-9322

ASIA/PACIFIC: LDC for ON Semiconductor - Asia Support

**Phone**: 1–303–675–2121 (Tue–Fri 9:00am to 1:00pm, Hong Kong Time)

Toll Free from Hong Kong & Singapore:

001-800-4422-3781 Email: ONlit-asia@hibbertco.com

JAPAN: ON Semiconductor, Japan Customer Focus Center

4-32-1 Nishi-Gotanda, Shinagawa-ku, Tokyo, Japan 141-0031

Phone: 81-3-5740-2700

Email: r14525@onsemi.com

ON Semiconductor Website: http://onsemi.com For additional information, please contact your local

Sales Representative.